**Vishay Semiconductors** 

## Thyristor High Voltage, Phase Control SCR, 40 A



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PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	25 A			
V <sub>DRM</sub> /V <sub>RRM</sub>	1200 V			
V <sub>TM</sub>	1.6 V			
I <sub>GT</sub>	35 mA			
TJ	-40 °C to 140 °C			
Package	3L TO-220AB			
Circuit configuration	Single SCR			

#### FEATURES

- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- 140 °C max. operating junction temperature
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding, and battery charge

#### DESCRIPTION

The VS-40TTS12... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 140 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I <sub>T(AV)</sub>	Sinusoidal waveform	25	٨		
I <sub>RMS</sub>		40	A		
V <sub>RRM</sub> /V <sub>DRM</sub>		1200	V		
I <sub>TSM</sub>		350	А		
V <sub>T</sub>	T <sub>J</sub> = 25 °C	1.6	V		
dV/dt		500	V/µs		
dl/dt		150	A/µs		
TJ		-40 to +140	°C		

VOLTAGE RATINGS			
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM PEAK DIRECT VOLTAGE V	TJ ℃
VS-40TTS12-M3	1200	1200	-25 to +140



FREE

### VS-40TTS12-M3



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CON	NDITIONS	VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	$T_{\rm C} = 93 ^{\circ}{\rm C},  180^{\circ}  {\rm conduct}$	tion half sine wave	25	
Maximum RMS on-state current	I <sub>RMS</sub>			40	А
Maximum peak, one-cycle	l	10 ms sine pulse, rated V	/ <sub>RRM</sub> applied	300	A
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no volt	age reapplied	350	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V	/ <sub>RRM</sub> applied	450	A <sup>2</sup> s
Maximum i-t for fusing	1-1	10 ms sine pulse, no volt	age reapplied	630	A-S
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 to 10 ms, no volta	6300	A²√s	
Maximum on-state voltage	V <sub>TM</sub>	80 A, T <sub>J</sub> = 25 °C		1.6	V
Low level value of on-state slope resistance	r <sub>t</sub>	T <sub>1</sub> = 140 °C		11.4	mΩ
Low level value of threshold voltage	V <sub>T(TO)</sub>	1) = 140 0		0.96	V
Maximum reverse and direct leakage	1 /1	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>RRM</sub> /V <sub>DRM</sub>	0.5	
current	I <sub>RRM</sub> /I <sub>DRM</sub>	T <sub>J</sub> = 140 °C	VR - naleu VRRM/ VDRM	12	
Holding current	Ι <sub>Η</sub>	Anode supply = 6 V, resistive load, initial $I_T$ = 1 A, $T_J$ = 25 °C		100	mA
Maximum latching current	١L	Anode supply = 6 V, resis	200		
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J max.$ , linear to 80 °C, $V_{DRM} = R_g - k = Open$		500	V/µs
Maximum rate of rise of turned-on current	dl/dt			150	A/µs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>		8.0	W
Maximum average gate power	P <sub>G(AV)</sub>		2.0	vv
Maximum peak positive gate current	+ I <sub>GM</sub>		1.5	А
Maximum peak negative gate voltage	- V <sub>GM</sub>		10	V
Maximum required DC gate current to trigger	I <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J$ = 25 °C	35	mA
Maximum required DC gate voltage to trigger	V <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J$ = 25 °C	1.3	V
Maximum DC gate voltage not to trigger	V <sub>GD</sub>	T <sub>.I</sub> = 140 °C, V <sub>DBM</sub> = Rated value	0.2	
Maximum DC gate current not to trigger	I <sub>GD</sub>	$T_{\rm J} = 140$ O, $v_{\rm DRM} = hated value$	1.5	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t <sub>gt</sub>	T <sub>J</sub> = 25 °C	0.9	
Typical reverse recovery time	t <sub>rr</sub>	T <sub>.1</sub> = 140 °C	4	μs
Typical turn-off time	t <sub>q</sub>	1j = 140 C	110	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to 140	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub> DC operation		0.8	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		60	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style 3L TO-220AB	40T	FS12

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Fig. 1 - Current Rating Characteristics



Fig. 2 - Current Rating Characteristics



Fig. 3 - On-State Power Loss Characteristics



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Fig. 4 - On-State Power Loss Characteristics



Fig. 5 - Maximum Non-Repetitive Surge Current



Fig. 6 - Maximum Non-Repetitive Surge Current

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### VS-40TTS12-M3







Instantaneous On-State Voltage (V)

Fig. 7 - On-State Voltage Drop Characteristics







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#### **ORDERING INFORMATION TABLE**

Device code	VS-	40	т	т	S	12	-M3
		(2)	(3)	4	(5)	(6)	(7)
	1	- Visł	nay Sem	niconduc	tors pro	duct	U
	2	- Cur	rent rati	ng, RMS	s value		
	3	- Circ	uit conf	iguratior	1:		
		T =	single tl	nyristor			
	4	- Pac	kage:				
	_	T =	TO-220				
	5	- Тур	e of silio	con:			
				d recove	•		
	6	- Volt	age rati	ng (12 =	1200 V	)	
	7	- Envi	ronmen	tal digit:			
		-M3	= halog	en-free,	RoHS-c	ompliar	nt, and t

ORDERING INFORMATION (Example)						
PREFERRED P/N         QUANTITY PER T/R         MINIMUM ORDER QUANTITY         PACKAGING DESCRIPTION						
VS-40TTS12-M3	50	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96154
Part marking information	www.vishay.com/doc?95028



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### **3L TO-220AB**

#### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@





SYMPOL	SYMBOL MILLIMETERS		INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC®	outline	TO-220AB
	ouume	10-220AD

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

#### Notes

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2 (minimum)

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 $<sup>^{(1)}\,</sup>$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(5)</sup> Controlling dimensions: inches



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 T201N70TOH
 T700N22TOF
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 NTE5427
 NTE5442

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